

C : Materials Science

Q. 1 – Q. 9 carry one mark each.

- Q.1 Energy Dispersive Spectroscopy (EDS) in a typical scanning electron microscope enables elemental identification by collecting and examining which of the following:
- (A) Secondary electrons from the sample
 - (B) Back scattered electrons from the sample
 - (C) Characteristic X-rays from the sample
 - (D) Diffraction pattern from the sample
- Q.2 Which of the following rotational symmetry is forbidden in a perfectly periodic 3-dimensional lattice?
- (A) 1-fold
 - (B) 3-fold
 - (C) 5-fold
 - (D) 6-fold
- Q.3 Which of the following thermodynamic properties shows a discontinuity during a second-order phase transition?
- (A) Volume
 - (B) Enthalpy
 - (C) Entropy
 - (D) Heat capacity
- Q.4 Cross slip is easily promoted in metals having
- (A) a low stacking fault energy.
 - (B) a low grain boundary energy.
 - (C) a high stacking fault energy.
 - (D) a high grain boundary energy.
- Q.5 For a typical metal at room temperature and atmospheric pressure, the Fermi energy is defined as the energy level for which the probability of occupancy is:
- (A) 0
 - (B) 0.25
 - (C) 0.5
 - (D) 1
- Q.6 Number of elements in a tensor of rank 4 is _____.
- Q.7 Which one of the following effects is the working principle of a thermocouple?
- (A) Thomson
 - (B) Seebeck
 - (C) Peltier
 - (D) Meissner
- Q.8 At equilibrium, the maximum number of phases that can coexist in a ternary system at constant pressure is _____.
- Q.9 Defect-free single crystal alumina (sapphire) is
- (A) opaque and white.
 - (B) transparent.
 - (C) translucent.
 - (D) opaque and black.

Q. 10 – Q. 22 carry two marks each.

Q.10 Match the following processes and the products obtained:

P: Mechanical attrition	1: Thin films
Q: Physical vapour deposition	2: Plastics
R: Injection moulding	3: Nanoparticles
S: Sintering	4: Rails
	5: Carbide tools

- (A) P-1, Q-2, R-3, S-5
 (B) P-3, Q-1, R-2, S-5
 (C) P-4, Q-1, R-3, S-2
 (D) P-3, Q-4, R-1, S-2

Q.11 In a diffraction experiment, monochromatic X-rays of wavelength 1.54 \AA are used to examine a material with a BCC structure. If the lattice parameter is 4.1 \AA , the angular position θ of the first diffraction peak is _____ degrees.

Q.12 The yield strength of a ferritic steel increases from 120 MPa to 150 MPa when the grain size is decreased from $256 \mu\text{m}$ to $64 \mu\text{m}$. When the grain size is further reduced to $16 \mu\text{m}$, the expected yield strength is _____ MPa.

Q.13 A direct bandgap semiconductor has a bandgap of 1.8 eV. The threshold value of the wavelength **BELOW** which this material will absorb radiation is _____ \AA .
 (Given: Planck's constant, $h = 6.626 \times 10^{-34} \text{ J s}$, the charge of an electron, $e = 1.6 \times 10^{-19} \text{ C}$, and speed of light, $c = 3 \times 10^8 \text{ m s}^{-1}$)

Q.14 A half cell consisting of pure Ni immersed in an aqueous solution containing Ni^{2+} ions of unknown concentration, is galvanically coupled with another half cell consisting of pure Cd immersed in a 1 M aqueous solution of Cd^{2+} ions. The temperature is $25 \text{ }^\circ\text{C}$ and pressure is 1 atm. The standard electrode reduction potentials of Ni and Cd are -0.250 V and -0.403 V , respectively. The voltage of the cell is found to be zero. The concentration of Ni^{2+} in the solution is _____ $\times 10^{-6} \text{ M}$.
 (Given: Universal gas constant, $R = 8.31 \text{ J mol}^{-1} \text{ K}^{-1}$, Faraday's constant, $F = 96500 \text{ C mol}^{-1}$)

Q.15 Match the type of magnetism given in Group 1 with the material given in Group 2:

<u>Group 1</u>	<u>Group 2</u>
P: Ferromagnetic	1: Nickel oxide
Q: Ferrimagnetic	2: Sodium
R: Antiferromagnetic	3: Magnetite
S: Paramagnetic	4: Cobalt

- (A) P-4, Q-3, R-1, S-2
 (B) P-4, Q-1, R-3, S-2
 (C) P-1, Q-2, R-4, S-3
 (D) P-3, Q-2, R-1, S-4

Q.16 Gallium is to be diffused into pure silicon wafer such that its concentration at a depth of 10^{-3} cm will be one half the surface concentration. Given that the diffusion coefficient (D) of gallium in silicon at $1355 \text{ }^\circ\text{C}$ is $6 \times 10^{-11} \text{ cm}^2 \text{ s}^{-1}$, the time the silicon wafer should be heated in contact with gallium vapour at $1355 \text{ }^\circ\text{C}$ is _____ s.
 (Given: $\text{erf}(0.5) \cong 0.5$)

- Q.17 A batch of spherical titania nanoparticles, uniform in size, has a specific surface area of $125 \text{ m}^2 \text{ g}^{-1}$. If the density of titania is 4.23 g cm^{-3} , the diameter of the particles is _____ nm.
- Q.18 Given the probability distribution function
$$f(x) = \begin{cases} 0.25x & \text{for } 1 \leq x \leq 3 \\ 0 & \text{otherwise} \end{cases}$$
The probability that the random variable x takes a value between 1 and $\sqrt{5}$ is _____.
- Q.19 In the vulcanization of 50 g of natural rubber, 10 g of sulfur is added. Assuming the mer to S ratio is 1:1, the maximum percentage of cross-linked sites that could be connected is _____%.
(Given: atomic weight of S is 32 amu and molecular weight of a mer of natural rubber is 68 amu)
- Q.20 Match the heat treatment process of steels given in Group 1 with the microstructural feature given in Group 2:
- | <u>Group 1</u> | <u>Group 2</u> |
|-----------------|-------------------------------|
| P: Quenching | 1: Bainite |
| Q: Normalizing | 2: Martensite |
| R: Tempering | 3: Pearlite |
| S: Austempering | 4: Iron carbide precipitates |
| | 5: Intermetallic precipitates |
- (A) P-2, Q-3, R-4, S-1 (B) P-3, Q-4, R-5, S-1
(C) P-4, Q-1, R-5, S-3 (D) P-2, Q-5, R-4, S-3
- Q.21 In the photoelectric effect, electrons are ejected
- (A) at all wavelengths, as long as the intensity of the incident radiation is above a threshold value.
(B) at all wavelengths, as long as the intensity of the incident radiation is below a threshold value.
(C) at all intensities, as long as the wavelength of the incident radiation is below a threshold value.
(D) at all intensities, as long as the wavelength of the incident radiation is above a threshold value.
- Q.22 The angle between [110] and [111] directions in the cubic system is _____ degrees.

END OF THE QUESTION PAPER